

DHG100X600NA

advanced

 $V_{RRM} = 600V$

 $I_{FAV} = 2x \quad 50 A$

 $t_{rr} = 35 \, \text{ns}$

High Performance Fast Recovery Diode Low Loss and Soft Recovery Parallel legs

Sonic Fast Recovery Diode

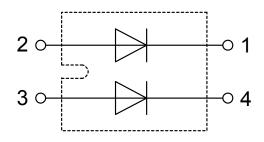
Part number

DHG100X600NA



Backside: Isolated





Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling





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Fast Diode					Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V _{RSM}	max. non-repetitive reverse blockii	ng voltage	$T_{VJ} = 25^{\circ}C$			600	V	
V _{RRM}	max. repetitive reverse blocking vo	oltage	$T_{VJ} = 25^{\circ}C$			600	V	
I _R	reverse current, drain current	V _R = 600 V	$T_{VJ} = 25^{\circ}C$			200	μΑ	
		$V_R = 600 V$	$T_{VJ} = 125^{\circ}C$			4	mΑ	
V _F	forward voltage drop	I _F = 50 A	$T_{VJ} = 25^{\circ}C$			2.20	V	
		I _F = 100 A				2.95	V	
		I _F = 50 A	T _{VJ} = 125°C			2.18	V	
		$I_F = 100 \text{ A}$				3.10	V	
I _{FAV}	average forward current	T _C = 60°C	T _{VJ} = 150°C			50	Α	
		rectangular d = 0.5					1 1	
V _{F0}	threshold voltage		T _{VJ} = 150°C			1.20	V	
r _F	slope resistance	ss calculation only				19	mΩ	
R _{thJC}	thermal resistance junction to case)				0.6	K/W	
R _{thCH}	thermal resistance case to heatsin	k			0.10		K/W	
P _{tot}	total power dissipation		$T_{C} = 25^{\circ}C$			210	W	
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			430	Α	
C	junction capacitance	V _R = 400 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		47		pF	
I _{RM}	max. reverse recovery current		T _{VJ} = 25°C		20		Α	
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}$	$T_{VJ} = 125$ °C		tbd		Α	
t _{rr}	reverse recovery time	-di _⊧ /dt = 1200 A/μs	$T_{VJ} = 25^{\circ}C$		35		ns	
		•	$T_{VJ} = 125$ °C		tbd		ns	

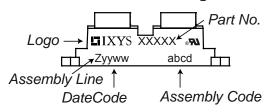


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Package SOT-227B (minibloc)		Ratings						
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					150	Α
T _{stg}	storage temperature				-40		150	°C
T _{VJ}	virtual junction temperatur	е			-40		150	°C
Weight						30		g
M _D	mounting torque				1.1		1.5	Nm
M_{τ}	terminal torque				1.1		1.5	Nm
d _{Spp/App}	creepage distance on surface striking distance through air		terminal to terminal	10.5	3.2			mm
d _{Spb/Apb}	creepage distance on sun	ace striking distance through an	terminal to backside	8.6	6.8			mm
V _{ISOL}	isolation voltage	t = 1 second	50/60 Hz, RMS; I _{ISOL} ≤ 1 mA		3000			V
		t = 1 minute			2500			٧

Product Marking



Part number

D = Diode

H = Sonic Fast Recovery Diode

G = extreme fast

100 = Current Rating [A]

X = Parallel legs

600 = Reverse Voltage [V]

NA = SOT-227B (minibloc)

Ordering	Part Number	Part Number Marking on Product		Quantity	Code No.	
Standard	DHG100X600NA	DHG100X600NA	Tube	10	510840	

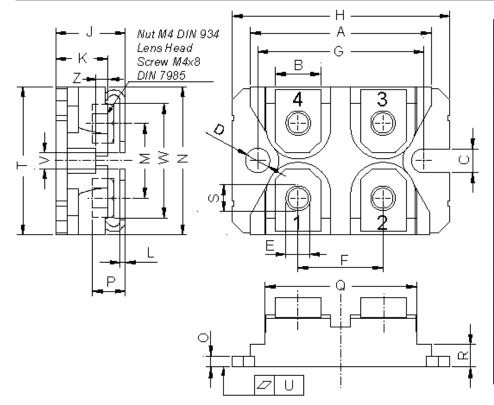
Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 150 ^{\circ}C$
$I \rightarrow V_0$	R_0	Fast Diode		
V _{0 max}	threshold voltage	1.2		V
R _{0 max}	slope resistance *	17		$m\Omega$



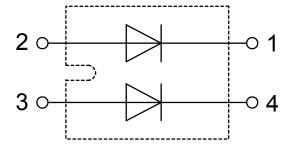


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Outlines SOT-227B (minibloc)



Dim.	Millir	Millimeter		hes
Dim.	min	max	min	max
Α	31.50	31.88	1.240	1.255
В	7.80	8.20	0.307	0.323
С	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
Е	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
Н	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
0	1.95	2.13	0.077	0.084
Р	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
Т	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Ζ	2.50	2.70	0.098	0.106



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